

5A, 50V - 1000V High Efficient Surface Mount Rectifier

FEATURES

- Glass passivated junction chip
- Ideal for automated placement
- Low forward voltage drop
- Low profile package
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer, automotive and telecommunication.

MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
I _{F(AV)}	5	А				
V _{RRM}	50 - 1000	V				
I _{FSM}	150	А				
T _{J MAX}	150	°C				
Package	DO-214AB (SMC)					
Configuration	Sing	le die				





DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	HS5A	HS5B	HS5D	HS5F	HS5G	HS5J	HS5K	HS5M	UNIT
Marking code on the device		HS5A	HS5B	HS5D	HS5F	HS5G	HS5J	HS5K	HS5M	
Repetitive peak reverse voltage	V _{RRM}	50	100	200	300	400	600	800	1000	V
Reverse voltage, total rms value	V _{R(RMS)}	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	300	400	600	800	1000	
Forward current	I _{F(AV)}				į	5				А
Surge peak forward current, 8.3 ms single half sine-wave uperimposed on rated load per diode	I _{FSM}	150		A						
Junction temperature	T_{J}	- 55 to +150			°C					
Storage temperature	T _{STG}	- 55 to +150			°C					



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-ambient thermal resistance	R _{eja}	60	°C/W

ELECTRICAL SPECIFIC		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Forward voltage per diode ⁽¹⁾	HS5A HS5B HS5D HS5F	I _F = 3A, T _J = 25°C	V _F	-	-	V
r onvara vonago por alodo	HS5G HS5J HS5K HS5M	n _F = 0, x, 1, j = 20 €	° F	-	- 1.35	V
	HS5A HS5B HS5D HS5F			-	1.00	V
Forward voltage per diode ⁽¹⁾	HS5G HS5J HS5K HS5M	I _F = 5A, T _J = 25°C	V _F	-	1.30 1.70	V V
Reverse current @ rated V _R per	diode ⁽²⁾	$T_J = 25^{\circ}C$	25°C		10	μA
		T _J = 125°C	·K	-	250	μΑ
Junction capacitance	HS5A HS5B HS5D HS5F HS5G	1 MHz, V _R =4.0V	CJ	80	-	pF
	HS5J HS5K HS5M			50	-	pF
Reverse recovery time	HS5A HS5B HS5D HS5F HS5G	I _F =0.5A , I _R =1.0A I _{RR} =0.25A	t _{rr}	-	50	ns
	HS5J HS5K HS5M			-	75	ns

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms



ORDERING INFORMATION						
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
		R7		SMC	850 / 7" Plastic reel	
		R6		SMC	3,000 / 13" Paper reel	
HS5x (Note 1,2)	н	M6	G	SMC	3,000 / 13" Plastic reel	
		V7		Matrix SMC	850 / 7" Plastic reel	
		V6		Matrix SMC	`3,000 / 13" Plastic reel	

Note :

1. "x" defines voltage from 50V (HS5A) to 1000V (HS5M)

2. Only V6 and V7 are all green compound (halogen free)

EXAMPLE					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
HS5AHR7G	HS5A	Н	R7	G	AEC-Q101 qualified Green compound



Fig.2 Typical Junction Capacitance

CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

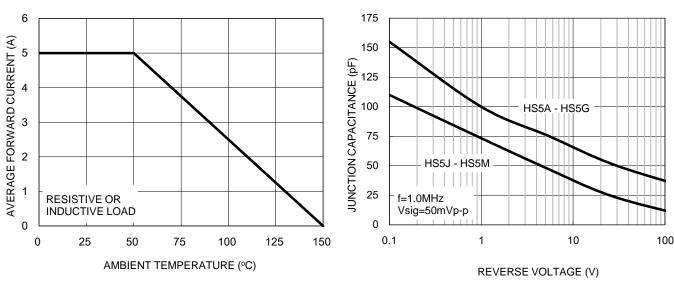
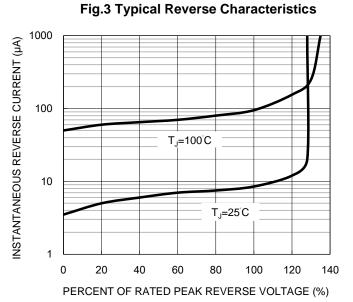
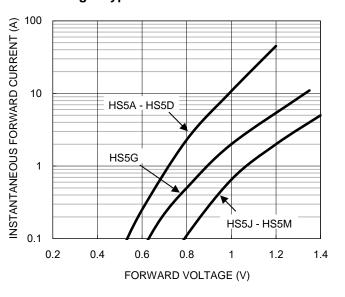


Fig.1 Forward Current Derating Curve

Fig.4 Typical Forward Characteristics







CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.5 Maximum Non-repetitive Forward Surge Current

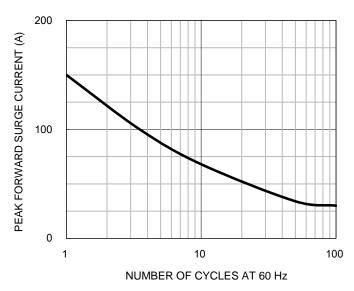
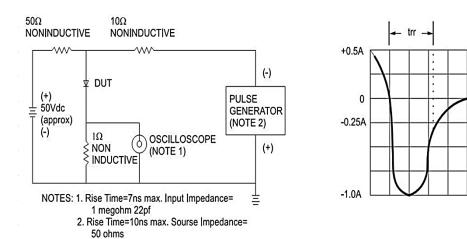


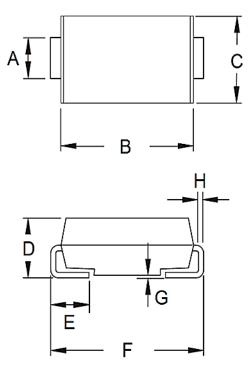
Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram





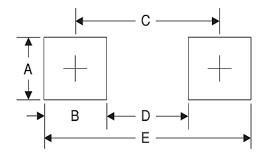
PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



DIM	DIM. Unit (mm)		Unit	(inch)	
DIN.	Min.	Max.	Min.	Max.	
А	2.90	3.20	0.114	0.126	
В	6.60	7.11	0.260	0.280	
С	5.59	6.22	0.220	0.245	
D	2.00	2.62	0.079	0.103	
E	1.00	1.60	0.039	0.063	
F	7.75	8.13	0.305	0.320	
G	0.10	0.20	0.004	0.008	
Н	0.15	0.31	0.006	0.012	

SUGGESTED PAD LAYOUT

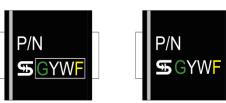


Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
E	9.40	0.370

MARKING DIAGRAM



SMC



- P/N =Marking Code
- G =Green Compound
- YW =Date Code
- F =Factory Code



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